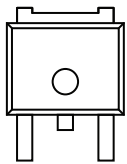


| PRODUCT SUMMARY | |
|--|--------|
| V _{DS} (V) | 50 |
| R _{DS(on)} (Ω) at V _{GS} = 10 V | 0.011 |
| R _{DS(on)} (Ω) at V _{GS} = 4.5 V | 0.015 |
| I _D (A) | 50 |
| Configuration | Single |

FEATURES

- TrenchFET® Power MOSFET
- Package with Low Thermal Resistance
- 100 % R_g and UIS Tested
- AEC-Q101 Qualified^d
- Material categorization:
For definitions of compliance please see
www.freescale.net.cn

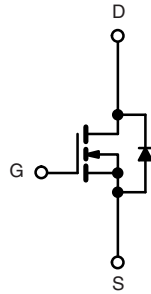
TO-252



G D S

Top View

Drain Connected to Tab



N-Channel MOSFET

| ORDERING INFORMATION | |
|---------------------------------|------------------|
| Package | TO-252 |
| Lead (Pb)-free and Halogen-free | SQD50N05-11L-GE3 |

| ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted) | | | |
|---|-----------------------------------|-------------------------------------|------|
| PARAMETER | SYMBOL | LIMIT | UNIT |
| Drain-Source Voltage | V _{DS} | 50 | V |
| Gate-Source Voltage | V _{GS} | ± 20 | |
| Continuous Drain Current | I _D | T _C = 25 °C ^a | 50 |
| | | T _C = 125 °C | 32 |
| Continuous Source Current (Diode Conduction) ^a | I _S | 50 | A |
| Pulsed Drain Current ^b | I _{DM} | 200 | |
| Single Pulse Avalanche Energy | E _{AS} | 101 | |
| Single Pulse Avalanche Current | I _{AS} | 45 | |
| Maximum Power Dissipation ^b | P _D | T _C = 25 °C | 75 |
| | | T _C = 125 °C | 25 |
| Operating Junction and Storage Temperature Range | T _J , T _{stg} | - 55 to + 175 | °C |

| THERMAL RESISTANCE RATINGS | | | |
|----------------------------|-------------------|-------|------|
| PARAMETER | SYMBOL | LIMIT | UNIT |
| Junction-to-Ambient | R _{thJA} | 60 | °C/W |
| Junction-to-Case (Drain) | R _{thJC} | 2.0 | |

Notes

- Package limited.
- Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %.
- When mounted on 1" square PCB (FR-4 material).
- Parametric verification ongoing.

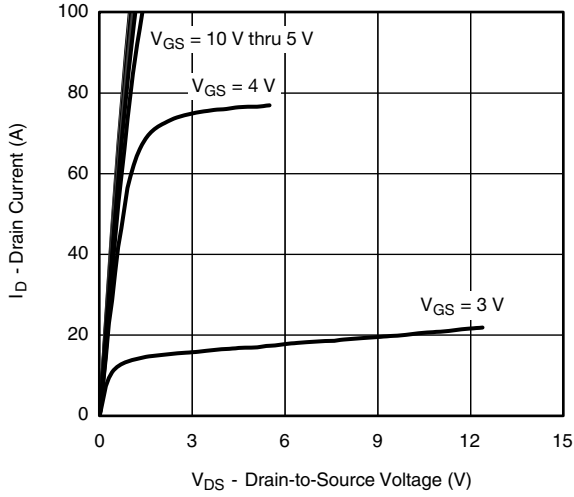
| SPECIFICATIONS ($T_C = 25\text{ }^\circ\text{C}$, unless otherwise noted) | | | | | | | |
|--|--------------|--|---|------|-------|-----------|---------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNIT |
| Static | | | | | | | |
| Drain-Source Breakdown Voltage | V_{DS} | $V_{GS} = 0\text{ V}, I_D = 250\text{ }\mu\text{A}$ | | 50 | - | - | V |
| Gate-Source Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = 250\text{ }\mu\text{A}$ | | 1.5 | 2.0 | 2.5 | |
| Gate-Source Leakage | I_{GSS} | $V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$ | | - | - | ± 100 | nA |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{GS} = 0\text{ V}$ | $V_{DS} = 50\text{ V}$ | - | - | 1.0 | μA |
| | | $V_{GS} = 0\text{ V}$ | $V_{DS} = 50\text{ V}, T_J = 125\text{ }^\circ\text{C}$ | - | - | 50 | |
| | | $V_{GS} = 0\text{ V}$ | $V_{DS} = 50\text{ V}, T_J = 175\text{ }^\circ\text{C}$ | - | - | 250 | |
| On-State Drain Current ^a | $I_{D(on)}$ | $V_{GS} = 10\text{ V}$ | $V_{DS} \geq 5\text{ V}$ | 50 | - | - | A |
| Drain-Source On-State Resistance ^a | $R_{DS(on)}$ | $V_{GS} = 10\text{ V}$ | $I_D = 45\text{ A}$ | - | 0.009 | 0.011 | Ω |
| | | $V_{GS} = 10\text{ V}$ | $I_D = 45\text{ A}, T_J = 125\text{ }^\circ\text{C}$ | - | - | 0.020 | |
| | | $V_{GS} = 10\text{ V}$ | $I_D = 45\text{ A}, T_J = 175\text{ }^\circ\text{C}$ | - | - | 0.024 | |
| | | $V_{GS} = 4.5\text{ V}$ | $I_D = 20\text{ A}$ | - | - | 0.015 | |
| Forward Transconductance ^b | g_{fs} | $V_{DS} = 15\text{ V}, I_D = 30\text{ A}$ | | - | 58 | - | S |
| Dynamic^b | | | | | | | |
| Input Capacitance | C_{iss} | $V_{GS} = 0\text{ V}$ | $V_{DS} = 25\text{ V}, f = 1\text{ MHz}$ | - | 1685 | 2106 | pF |
| Output Capacitance | C_{oss} | | | - | 345 | 430 | |
| Reverse Transfer Capacitance | C_{rss} | | | - | 144 | 180 | |
| Total Gate Charge ^c | Q_g | $V_{GS} = 10\text{ V}$ | $V_{DS} = 25\text{ V}, I_D = 43\text{ A}$ | - | 34.6 | 52 | nC |
| Gate-Source Charge ^c | Q_{gs} | | | - | 5.5 | 9 | |
| Gate-Drain Charge ^c | Q_{gd} | | | - | 9.1 | 14 | |
| Gate Resistance | R_g | $f = 1\text{ MHz}$ | | 1.3 | 2.6 | 3.9 | Ω |
| Turn-On Delay Time ^c | $t_{d(on)}$ | $V_{DD} = 25\text{ V}, R_L = 0.6\text{ }\Omega$ $I_D \cong 43\text{ A}, V_{GEN} = 10\text{ V}, R_g = 1\text{ }\Omega$ | | - | 8.5 | 13 | ns |
| Rise Time ^c | t_r | | | - | 11.5 | 18 | |
| Turn-Off Delay Time ^c | $t_{d(off)}$ | | | - | 22.5 | 34 | |
| Fall Time ^c | t_f | | | - | 7.5 | 12 | |
| Source-Drain Diode Ratings and Characteristics^b | | | | | | | |
| Pulsed Current ^a | I_{SM} | | | - | - | 200 | A |
| Forward Voltage | V_{SD} | $I_F = 45\text{ A}, V_{GS} = 0\text{ V}$ | | - | 0.95 | 1.5 | V |

Notes

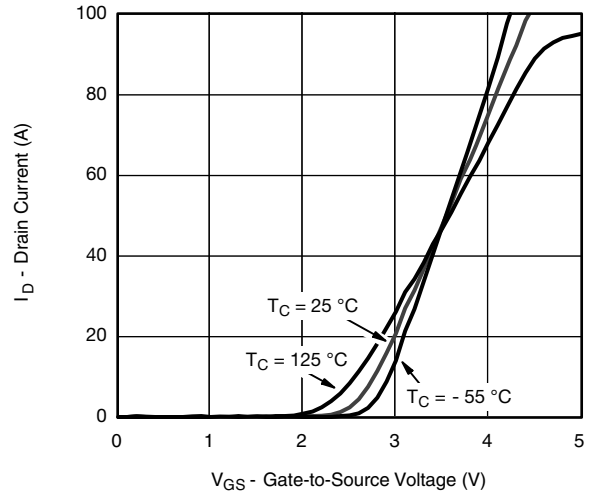
- Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
- Guaranteed by design, not subject to production testing.
- Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

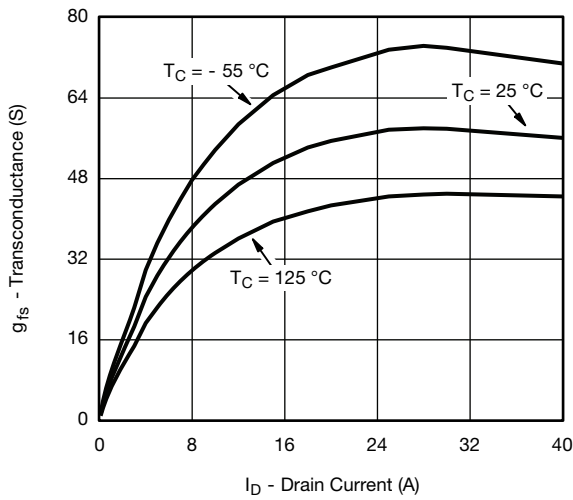
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



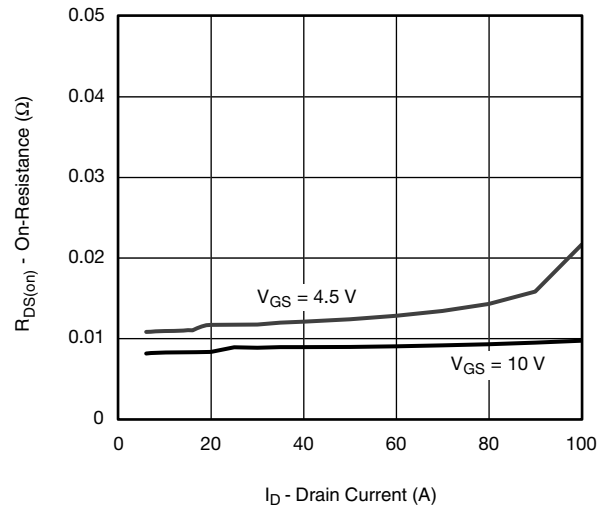
Output Characteristics



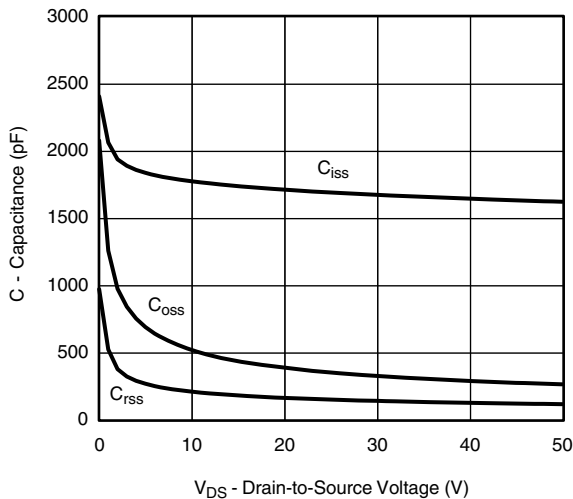
Transfer Characteristics



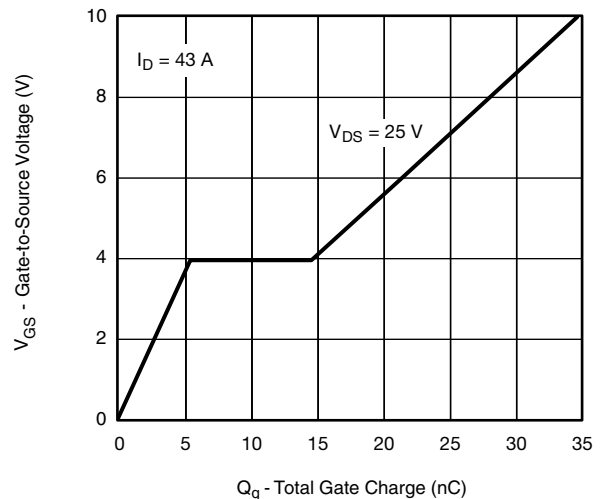
Transconductance



On-Resistance vs. Drain Current

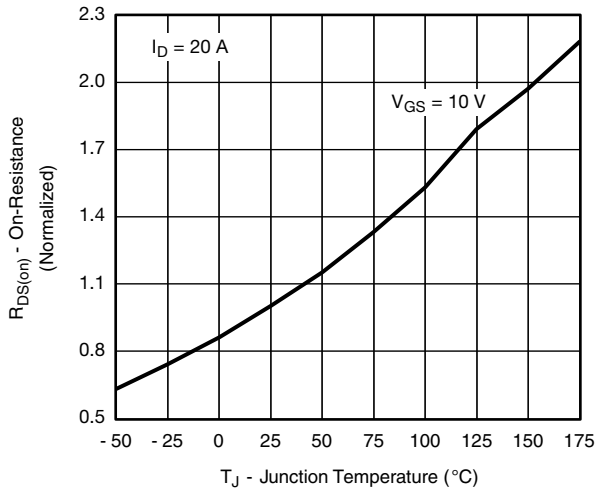


Capacitance

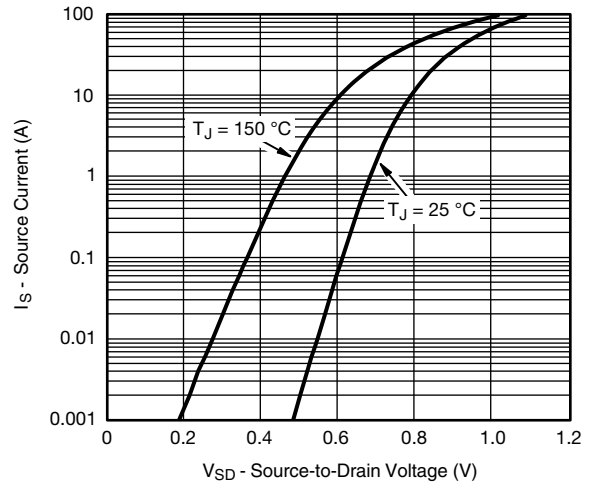


Gate Charge

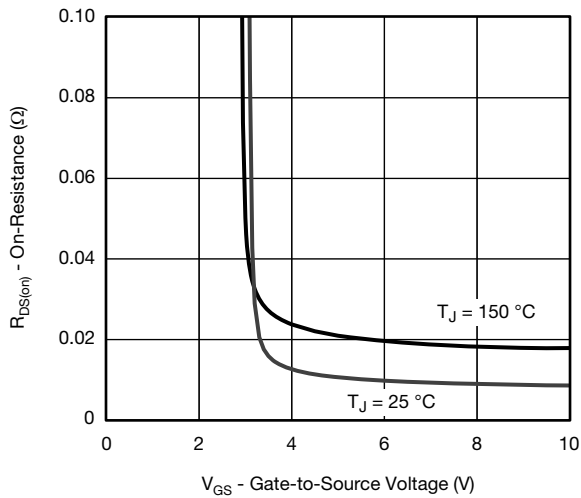
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



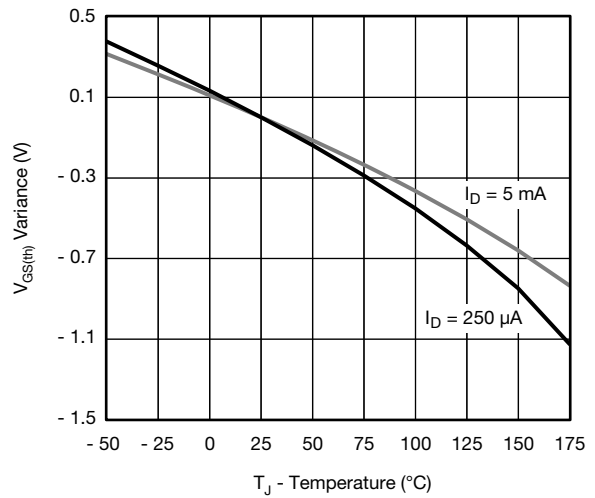
On-Resistance vs. Junction Temperature



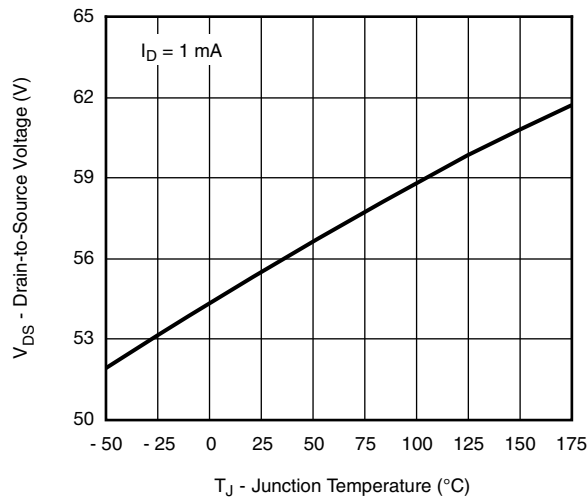
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage

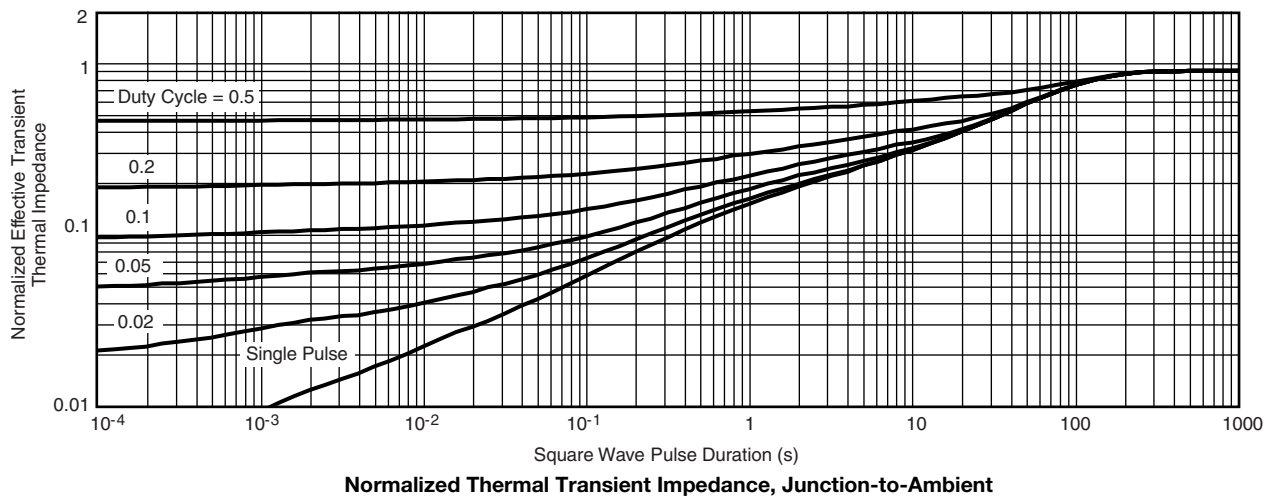
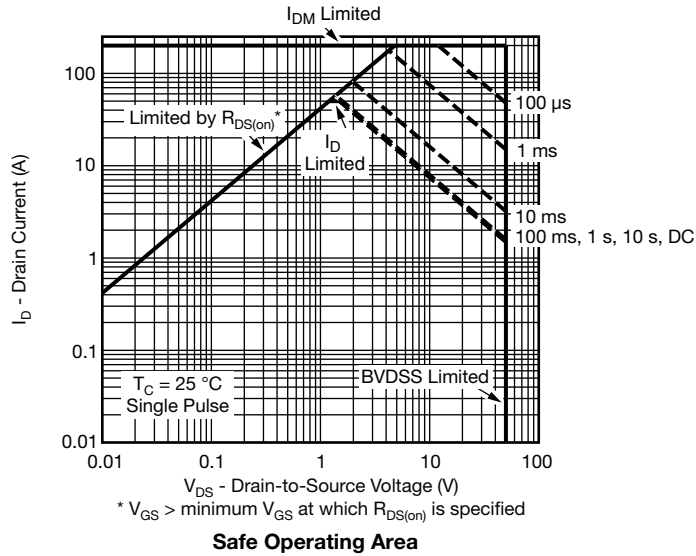


Threshold Voltage

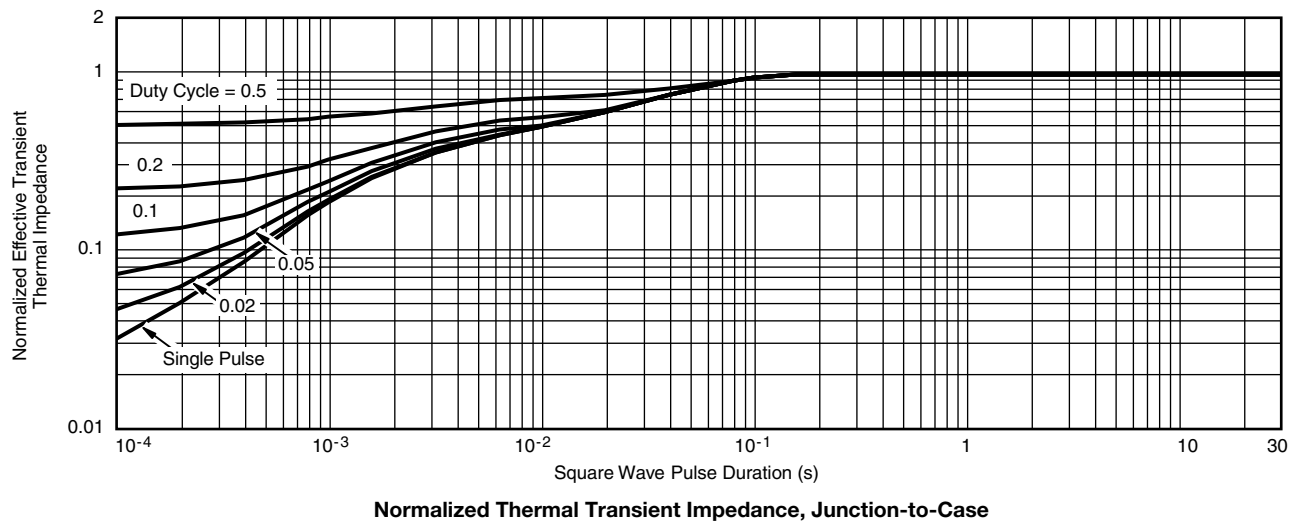


Drain Source Breakdown vs. Junction Temperature

THERMAL RATINGS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



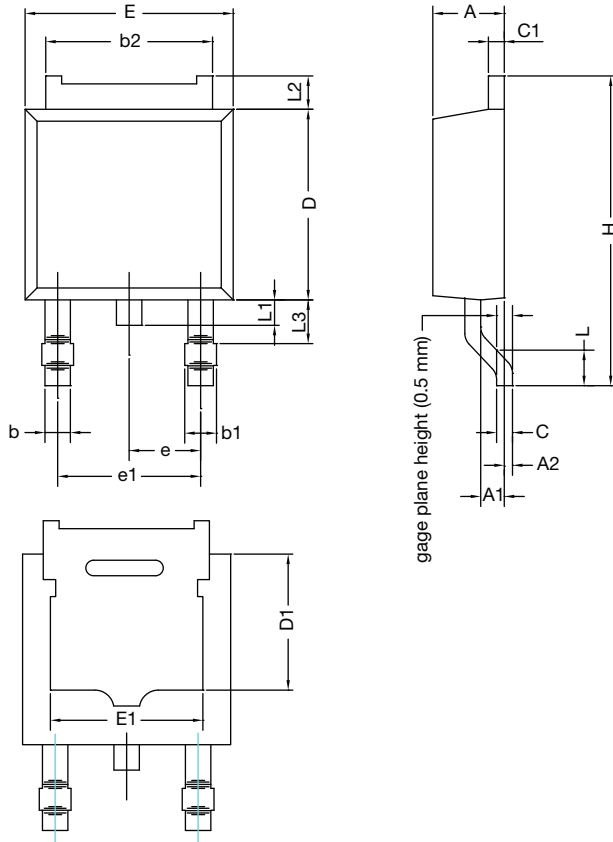
THERMAL RATINGS ($T_A = 25\text{ °C}$, unless otherwise noted)



Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)
 are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

TO-252AA CASE OUTLINE



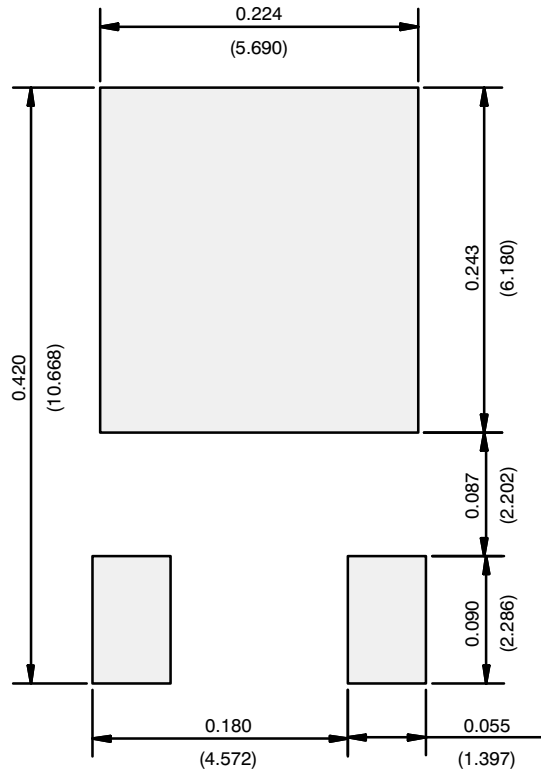
| DIM. | MILLIMETERS | | INCHES | |
|------|-------------|-------|-----------|-------|
| | MIN. | MAX. | MIN. | MAX. |
| A | 2.21 | 2.38 | 0.087 | 0.094 |
| A1 | 0.89 | 1.14 | 0.035 | 0.045 |
| A2 | 0.030 | 0.127 | 0.001 | 0.005 |
| b | 0.71 | 0.88 | 0.028 | 0.035 |
| b1 | 0.76 | 1.14 | 0.030 | 0.045 |
| b2 | 5.23 | 5.44 | 0.206 | 0.214 |
| C | 0.46 | 0.58 | 0.018 | 0.023 |
| C1 | 0.46 | 0.58 | 0.018 | 0.023 |
| D | 5.97 | 6.22 | 0.235 | 0.245 |
| D1 | 4.10 | 4.45 | 0.161 | 0.175 |
| E | 6.48 | 6.73 | 0.255 | 0.265 |
| E1 | 4.49 | 5.50 | 0.177 | 0.217 |
| e | 2.28 BSC | | 0.090 BSC | |
| e1 | 4.57 BSC | | 0.180 BSC | |
| H | 9.65 | 10.41 | 0.380 | 0.410 |
| L | 1.40 | 1.78 | 0.055 | 0.070 |
| L1 | 0.64 | 1.02 | 0.025 | 0.040 |
| L2 | 0.89 | 1.27 | 0.035 | 0.050 |
| L3 | 1.15 | 1.52 | 0.040 | 0.060 |

ECN: T11-0110-Rev. L, 18-Apr-11
DWG: 5347

Note

- Dimension L3 is for reference only.

RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads
Dimensions in Inches/(mm)

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